

Features

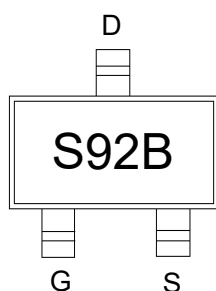
- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity
- Fast switching and soft recovery

Application

- Consumer electronic power supply
- Motor control
- Synchronous-rectification
- Isolated DC/DC convertor

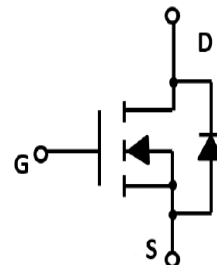
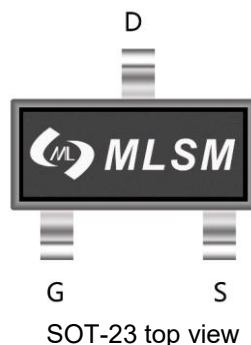
Product Summary

V_{DS}	$R_{DS(on)}$ MAX	I_D MAX
100V	160mΩ@10V	2.17A
	167mΩ@7.5V	



S92B: Device code

Marking and pin assignment



Schematic diagram



Halogen-Free

Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings ($T_C=25^{\circ}\text{C}$ Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
T_J	Maximum Junction Temperature	150	$^{\circ}\text{C}$
T_{STG}	Storage Temperature Range	-55 to 150	$^{\circ}\text{C}$
I_S	Diode Continuous Forward Current	$T_C=25^{\circ}\text{C}$ 2	A

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_C=25^{\circ}\text{C}$ 8	A
I_D	Continuous Drain Current	$T_C=25^{\circ}\text{C}$ 2.17	A
P_D	Maximum Power Dissipation	$T_C=25^{\circ}\text{C}$ 1.6	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	83	$^{\circ}\text{C/W}$

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
Si2122DS	SOT-23	S92B	3,000	45,000	180,000	7"reel

Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	100	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =100V, V _{GS} =0V	--	--	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	2	--	4	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =2.5A	--	133	160	mΩ
		V _{GS} =7.5V, I _D =2A	--	139	167	mΩ

Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)

C _{ISS}	Input Capacitance	V _{DS} =50V, V _{GS} =0V, f=1MHz	--	210	--	pF
C _{OSS}	Output Capacitance		--	28	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	6.2	--	pF

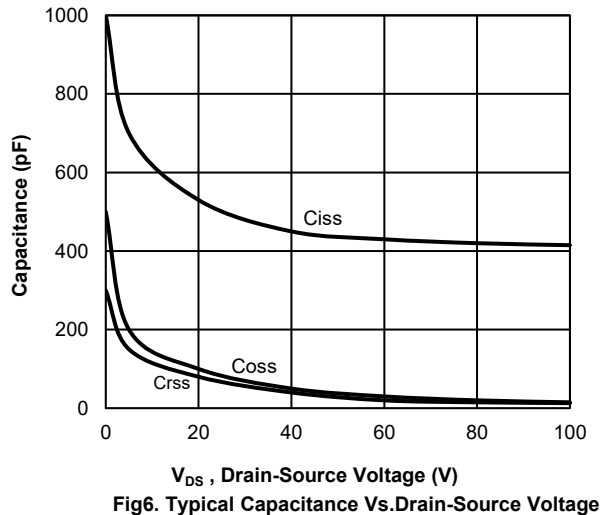
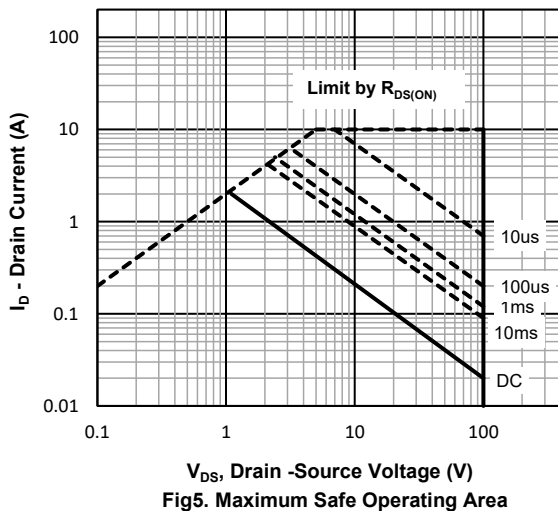
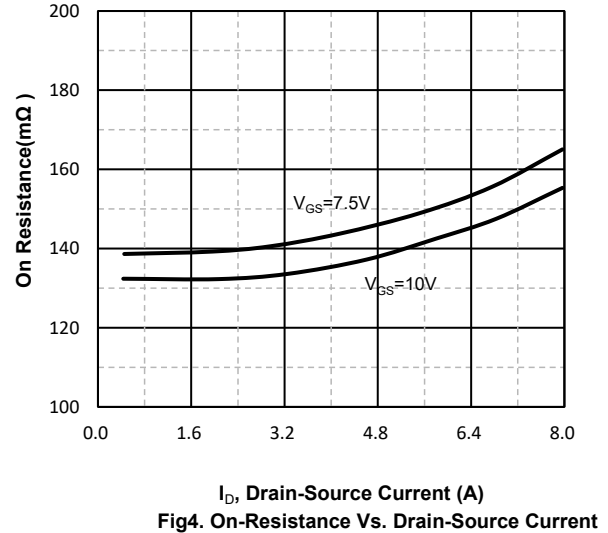
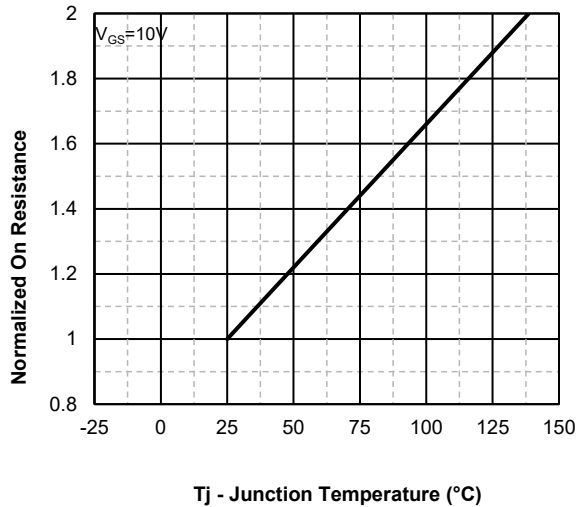
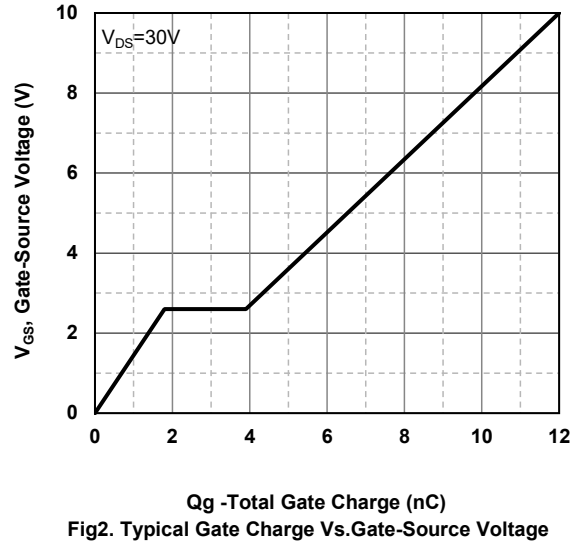
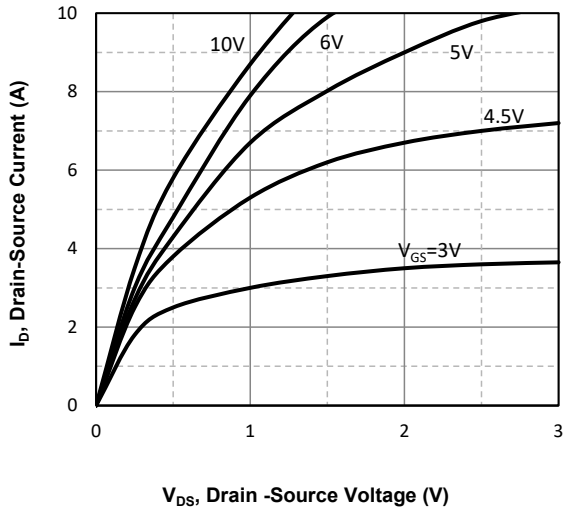
Switching Characteristics

Q _g	Total Gate Charge	V _{DS} =50V, I _D =2A, V _{GS} =4.5V	--	2.9	--	nC
Q _{gs}	Gate Source Charge		--	1.3	--	nC
Q _{gd}	Gate Drain Charge		--	0.6	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =50V, I _D =2A, R _L =25Ω, V _{GS} =10V, R _G =1Ω	--	7	--	nS
t _r	Turn-on Rise Time		--	4	--	nS
t _{d(off)}	Turn-Off Delay Time		--	10	--	nS
t _f	Turn-Off Fall Time		--	3	--	nS

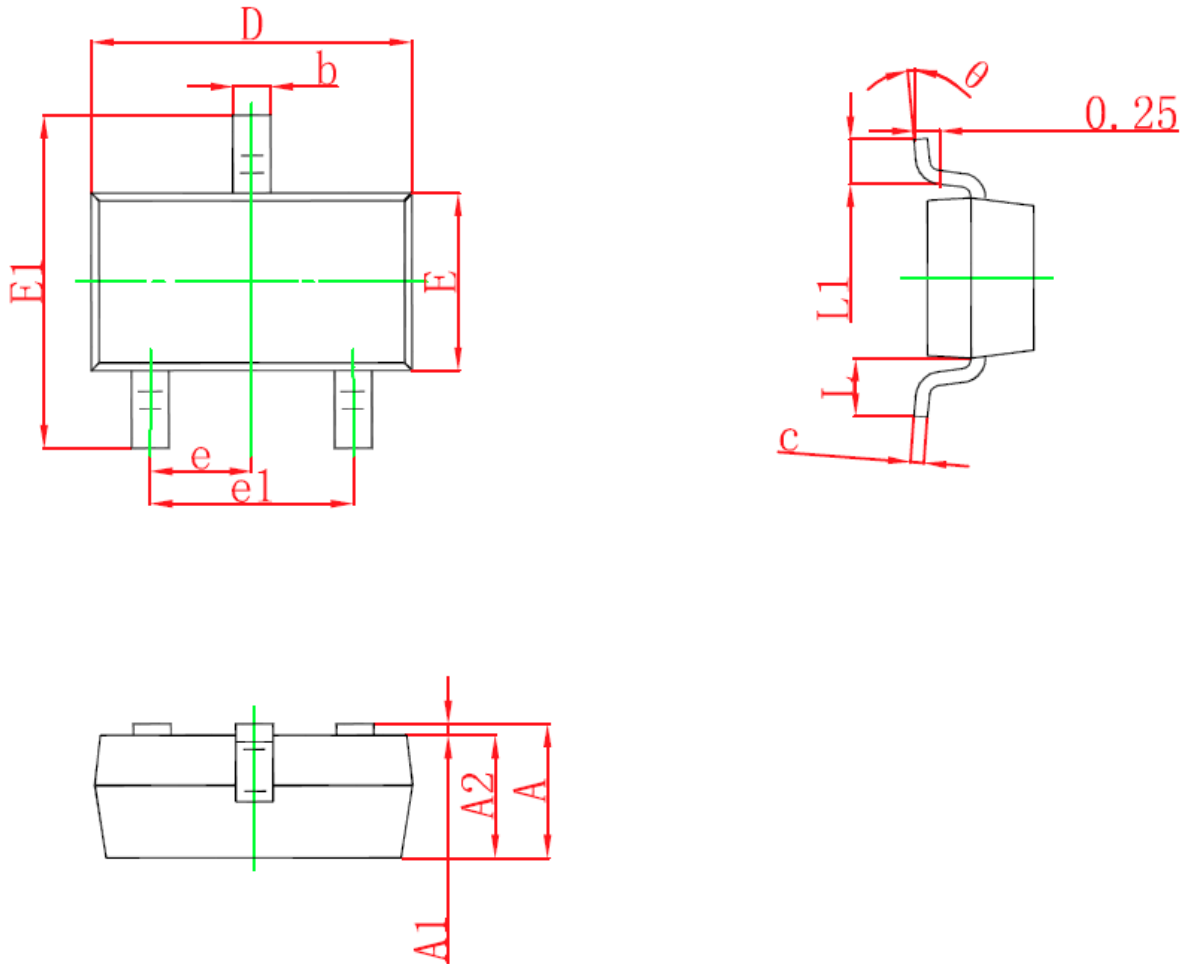
Source- Drain Diode Characteristics

V _{SD}	Forward on voltage	T _J =25°C, I _S =1.3A,	--	0.85	1.2	V
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Typical Operating Characteristics



SOT-23 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550REF		0.022REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°